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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/757,099	01/08/2001	Michael Geva	GEVA 6-2-4-21	6929
27964	7590	09/20/2005	EXAMINER	
HITT GAINES P.C. P.O. BOX 832570 RICHARDSON, TX 75083			WANG, GEORGE Y	
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			2871	

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Please find below and/or attached an Office communication concerning this application or proceeding.

DETAILED ACTION

Claim Rejections - 35 USC § 103

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

2. Claims 1 and 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Burnham et al. (U.S. Patent No. 4,546,480, from hereinafter "Burnham") in view of Beernink et al. (U.S. Patent No. 5,708,674, from hereinafter "Beernink").

Burnham discloses an electronic device and method of making an electronic device having an active region (fig. 4, ref. 38) located over a substrate (fig. 4, ref. 32). Burnham teaches an undoped layer with a barrier region made up of a number of

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barrier layers between a plurality of undoped layers (col. 5, lines 48-56) that does not form a portion of the active region.

However, the reference fails to specifically disclose that the active layer is under the barrier layer.

Beernink discloses an electronic device having an active layer (fig. 3, ref. 13) situated beneath a barrier layer.

It would have been obvious to one of ordinary skill in the art at the time the invention was made to have disposed the active layer beneath the barrier layer since one would be motivated to create a device with minimal layers (col. 2, lines 30-35). By preventing unwanted layers, fabrication would not only be more cost effective and more readily manufactured, it would prevent unwanted introductions of impurity. This would ultimately enhance reliability and minimize accompanying drawbacks (col. 3, lines 1-4).

3. Claims 2-8 and 10-16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Burnham and Beernink in view of DePoorter (WO 97/50133).

Burnham discloses an electronic device and method of making an electronic device having an active region (fig. 4, ref. 36) located over a substrate (fig. 4, ref. 32). Burnham teaches an undoped layer with a barrier region made up of a number of barrier layers between a plurality of undoped layers (col. 5, lines 48-56). Furthermore, the reference discloses barrier layers composed of aluminum arsenide with 5-50% aluminum composition (col. 5, lines 48-56), and having a thickness of about 1 nm and where the undoped layers each have a thickness of about 10 nm (col. 1, lines 23-34).

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The Burnham reference also teaches that there are no p-n junctions between the barrier and doped cladding.

Although the reference teaches a doped upper cladding (fig. 4, ref. 41), Burnham does not disclose it as being doped with zinc. Furthermore, the reference does not specifically teach the barrier region inhibiting the diffusion of zinc into the active region.

DePoorter discloses a semiconductor diode with an upper cladding doped with zinc (abstract). Furthermore, the reference teaches a barrier region that inhibits the diffusion of zinc into the active region (pg. 3, lines 21-35).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to have doped the upper cladding with zinc and to construct zinc-inhibitive properties to the barrier layers since one would be motivated to alternatively have a high and low bandgap value (pg. 3, lines 21-35). Such values render the barrier layers highly effective and reliable in practice since zinc-inhibition in the layers encourage highly thin layers that have mechanical stress without the defects caused by degradation of charged ions, such as zinc atoms (pg. 3, lines 21-35).

Response to Arguments

4. Applicant's arguments filed June 28, 2005 have been fully considered but they are not persuasive.

Applicant's main argument is that the prior art references do not teach an undoped barrier region layer over the active region. In particular, Applicant asserts that the barrier region cited in the Burnham reference is not a barrier region because

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Burnham refers to them as "active layers," but concedes that even if they were, the "so-called barrier region is located below the active region in Burnham" and argues that there is no undoped layer above the active region. While Applicant is correct in arguing that the barrier layer is not above the active layer, Applicant misses the fact that the barrier layers are in fact undoped (fig. 4 clearly says the barrier region is comprised of alternating layers that are "undoped"). Thus, the only deficiency in Burnham is that the barrier layer is under the active region. However, the Beernink reference remedies the deficiency in Burnham by teaching an electronic device having an active layer (fig. 3, ref. 13) situated beneath a barrier layer. As a result, Applicant's argument that the Beernink reference does not teach undoped layers is not relevant because the Beernink reference was used only to show that the undoped barrier region of Burnham could be over the active region.

As a result, Applicant's arguments do not place the application in condition for allowance and rejection is proper.

Conclusion

5. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the

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shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to George Y. Wang whose telephone number is 571-272-2304. The examiner can normally be reached on M-F, 8 am - 4:30 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert H. Kim can be reached on 571-272-2293. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

gw
September 19, 2005


JUNG T. NGUYEN
PRIMARY EXAMINER